

**Description**

The SX120P03D uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

**General Features**

$V_{DS} = -30V$   $I_D = -120A$

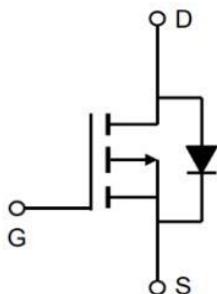
$R_{DS(ON)} < 5.5m\Omega$  @  $V_{GS} = -10V$

**Application**

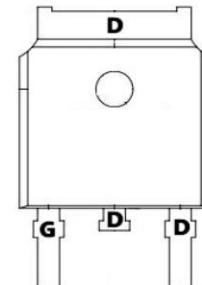
Lithium battery protection

Wireless impact

Mobile phone fast charging



TO-252-3L

**Absolute Maximum Ratings (TC=25°C unless otherwise noted)**

Symbol	Parameter	Max.	Units
VDSS	Drain-Source Voltage	-30	V
VGSS	Gate-Source Voltage	$\pm 20$	V
ID	Continuous Drain Current $T_c = 25^\circ C$	-120	A
ID	Continuous Drain Current $T_c = 100^\circ C$	-65	A
IDM	Pulsed Drain Current <sup>note1</sup>	-400	A
EAS	Single Pulsed Avalanche Energy <sup>note2</sup>	225	mJ
PD	Power Dissipation $T_c = 25^\circ C$	103	W
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	1.46	°C/W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-55 to +175	°C

**Electrical Characteristics ( $T_J=25^\circ\text{C}$ , unless otherwise noted)**

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V(BR)DSS	Drain-Source Breakdown Voltage	VGS=0V, ID= -250μA	-30	-33	-	V
IDSS	Zero Gate Voltage Drain Current	VDS= -30V, VGS=0V,	-	-	-1	μA
IGSS	Gate to Body Leakage Current	VDS=0V, VGS= ±20V	-	-	±100	nA
VGS(th)	Gate Threshold Voltage	VDS=VGS, ID= -250μA	-1.0	-1.6	-2.5	V
RDS(on)	Static Drain-Source on-Resistance	VGS= -10V, ID= -30A	-	3.8	5.5	mΩ
		VGS= -4.5V, ID= -20A	-	5.8	8.2	
Ciss	Input Capacitance	VDS= -15V, VGS=0V, f=1.0MHz	-	9400	-	pF
Coss	Output Capacitance		-	1000	-	pF
Crss	Reverse Transfer Capacitance		-	767	-	pF
Qg	Total Gate Charge	VDS= -15V, ID= -30A, VGS= -10V	-	42	-	nC
Qgs	Gate-Source Charge		-	8.4	-	nC
Qgd	Gate-Drain("Miller") Charge		-	11.2	-	nC
td(on)	Turn-on Delay Time	VDD= -15V, ID= -30A, VGS= -10V, RGEN=2.5Ω	-	15	-	ns
tr	Turn-on Rise Time		-	16	-	ns
td(off)	Turn-off Delay Time		-	69	-	ns
tf	Turn-off Fall Time		-	27	-	ns
IS	Maximum Continuous Drain to Source	DiodeForward Current	-	-	-90	A
ISM	Maximum Pulsed Drain to Source	Diode Forward Current	-	-	-360	A
VSD	Drain to Source Diode Forward Voltage	VGS=0V, IS= -30 A		-0.8	-1.2	V

**Notes:**

- 1、The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width  $\leq 300\mu\text{s}$  , duty cycle  $\leq 2\%$
- 3、The EAS data shows Max. rating . The test condition is  $T_J =25^\circ\text{C}$ ,  $V_{DD} = -15V$ ,  $V_G = -10V$ ,  $R_G =25\Omega$ ,  $L=0.5\text{mH}$ ,  $I_{AS} = -30\text{A}$
- 4、The power dissipation is limited by  $150^\circ\text{C}$  junction temperature
- 5、The data is theoretically the same as  $I_D$  and  $I_{DM}$  , in real applications , should be limited by total power dissipation.

## Typical Characteristics

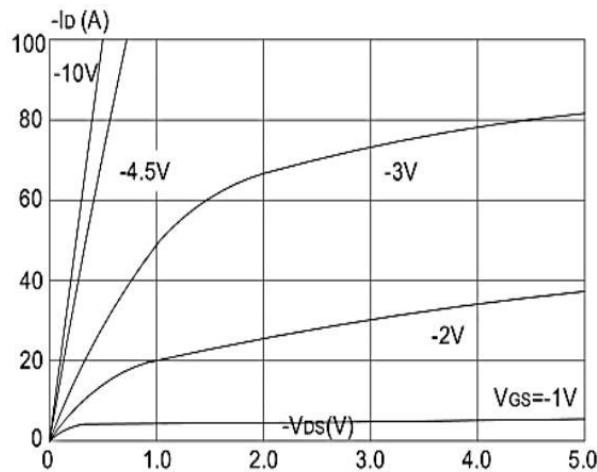


Figure 1: Output Characteristics

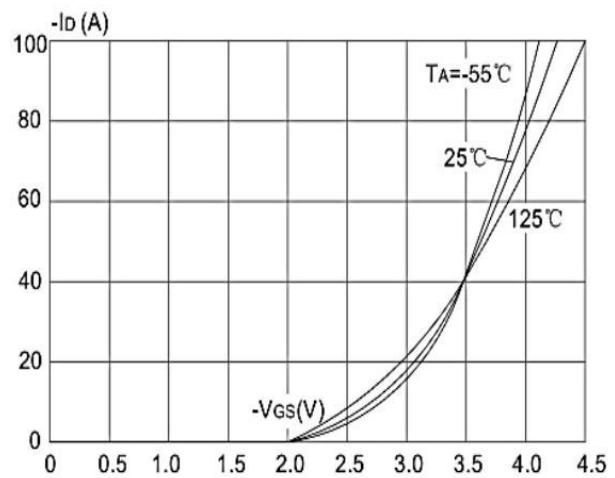


Figure 2: Typical Transfer Characteristics

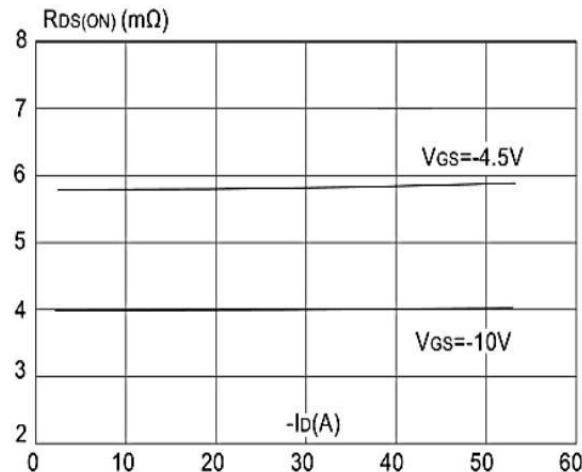


Figure 3: On-resistance vs. Drain Current

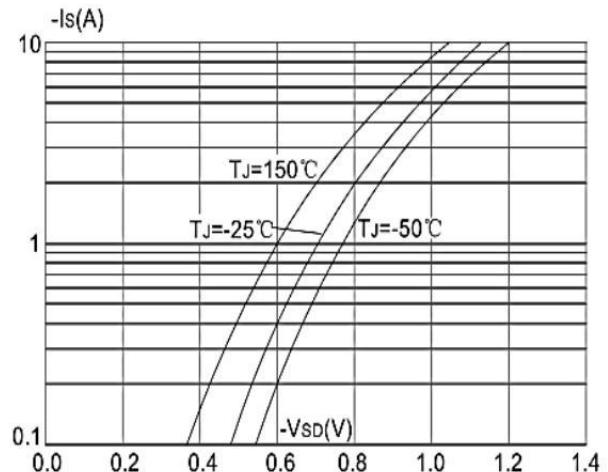


Figure 4: Body Diode Characteristics

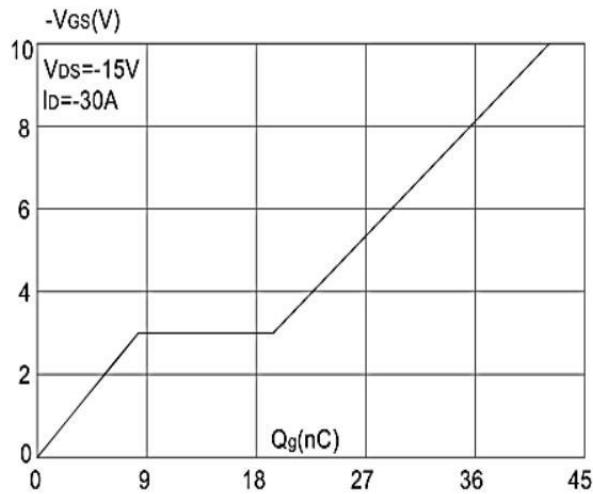


Figure 5: Gate Charge Characteristics

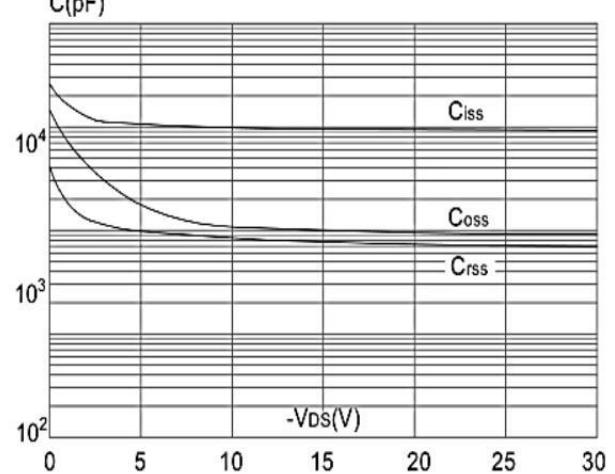


Figure 6: Capacitance Characteristics

## Typical Characteristics

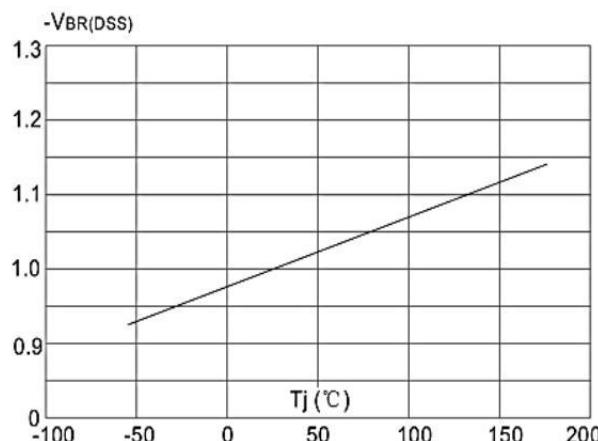


Figure 7: Normalized Breakdown Voltage vs.  
Junction Temperature

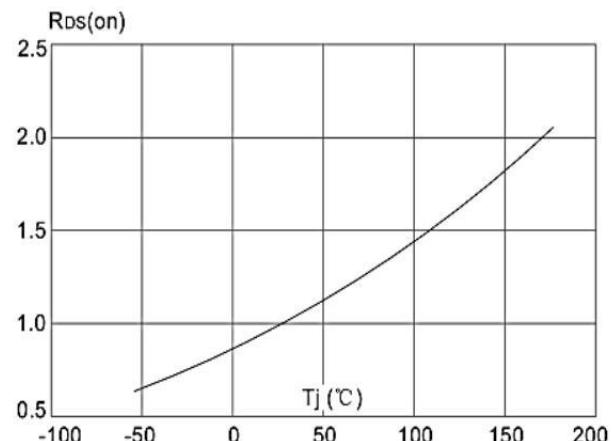


Figure 8: Normalized on Resistance vs.  
Junction Temperature

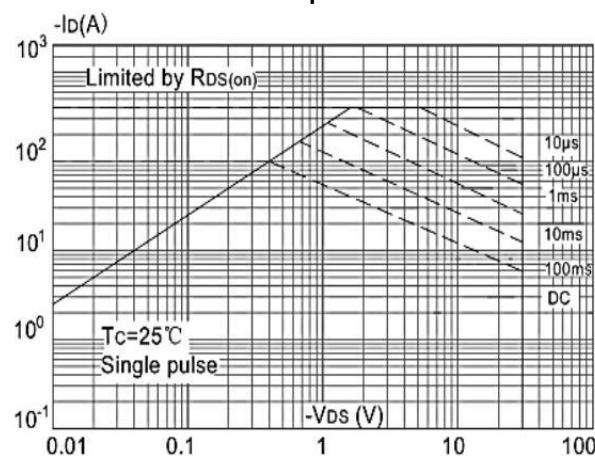


Figure 9: Maximum Safe Operating Area

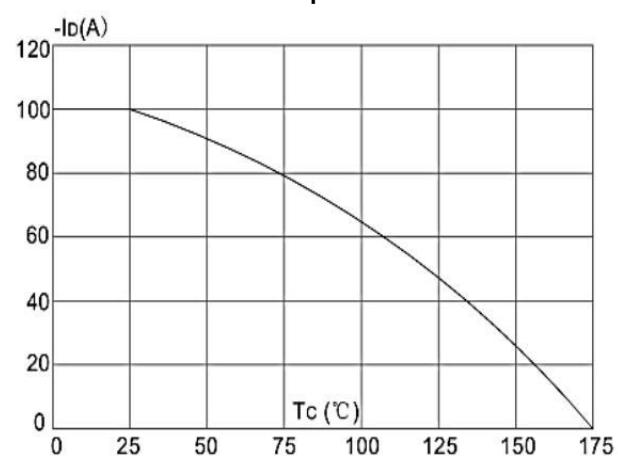


Figure 10: Maximum Continuous Drain Current  
vs. Case Temperature

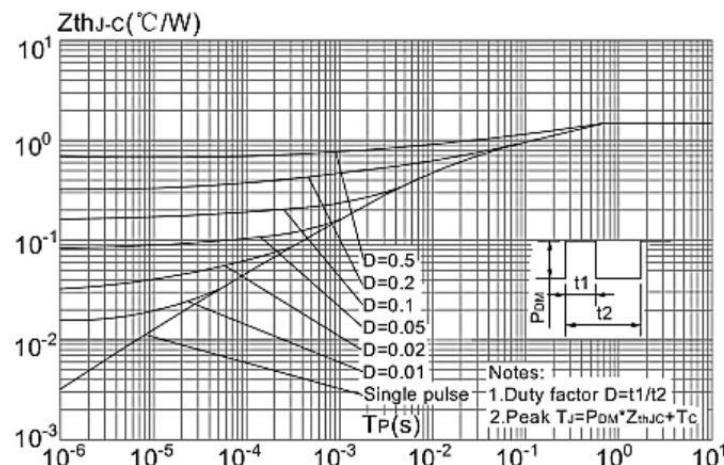
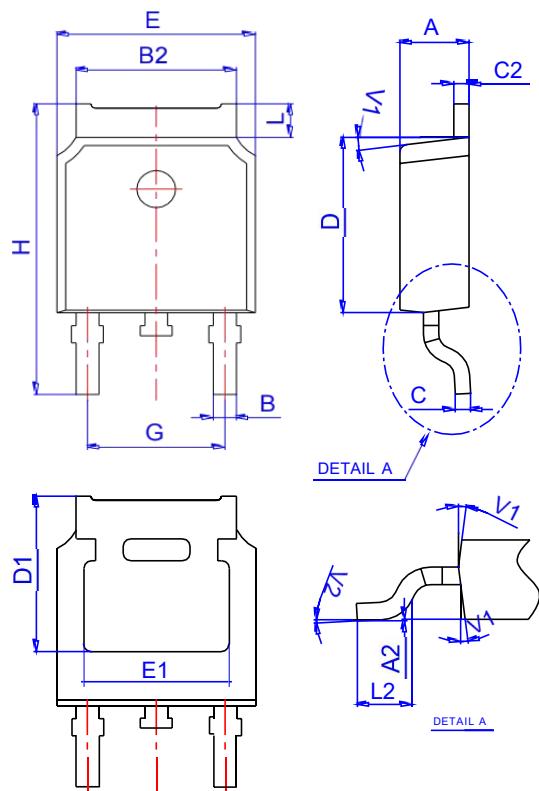


Figure 11: Maximum Effective  
Transient Thermal Impedance, Junction-to-Case

## Package Mechanical Data:TO-252-3L



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

### Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	TO-252-3L		2500